

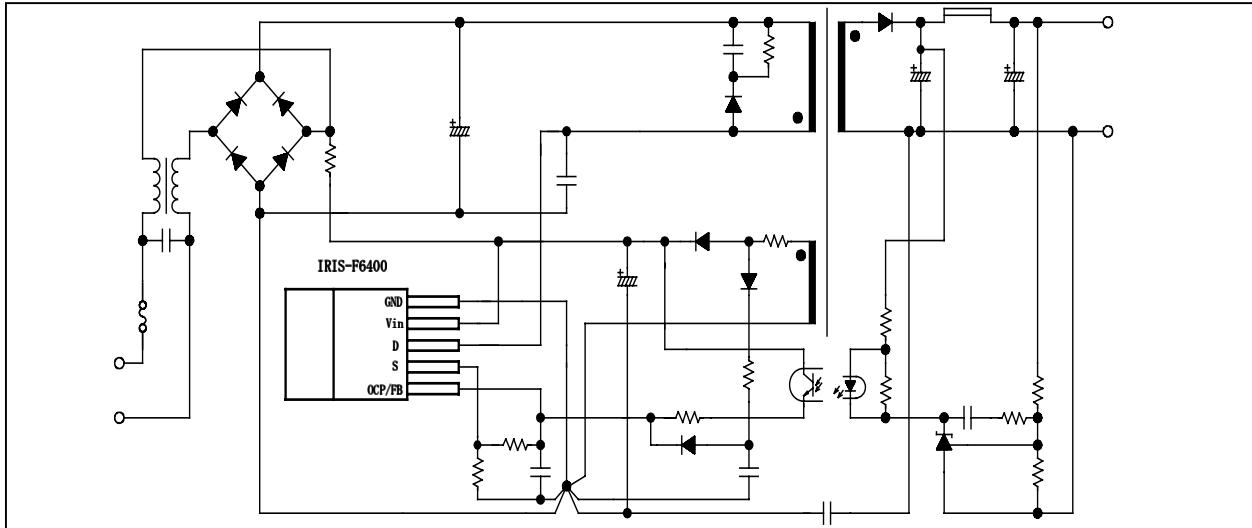
Features

- Oscillator is provided on the monolithic control with adopting On-Chip Trimming technology.
- Small temperature characteristics variation by adopting a comparator to compensate for temperature on the control part.
- Low start-up circuit current (100uA max)
- Built-in Active Low-Pass Filter for stabilizing the operation in case of light load
- Avalanche energy guaranteed MOSFET with high VDSS
- The built-in power MOSFET simplifies the surge absorption circuit since the MOSFET guarantees the avalanche energy.
- No VDSS de-rating is required.
- Built-in constant voltage drive circuit
- Built-in step drive circuit
- Built-in low frequency PRC mode ($\approx 20\text{kHz}$)
- Various kinds of protection functions
- Pulse-by-pulse Overcurrent Protection (OCP)
- Overvoltage Protection with latch mode (OVP)
- Thermal Shutdown with latch mode (TSD)

Descriptions

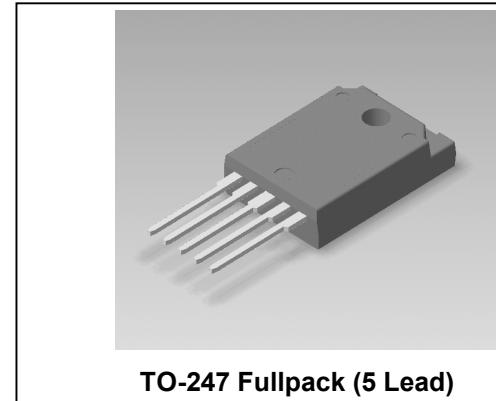
IRIS-F6426S is a hybrid IC consists from power MOSFET and a controller IC, designed for Quasi-Resonant (including low frequency PRC) fly-back converter type SMPS (Switching Mode Power Supply) applications. This IC realizes high efficiency, low noise, downsizing and standardizing of a power supply system reducing external components count and simplifying the circuit designs. (Note). PRC is abbreviation of “Pulse Ratio Control” (On-width control with fixed OFF-time).

Typical Connection Diagram



INTEGRATED SWITCHER

Package Outline



TO-247 Fullpack (5 Lead)

Key Specifications

Type	MOSFET VDSS(V) MAX	RDS(ON) MAX	AC input(V)	Pout(W) Note 1
IRIS-F6426S	450	0. 58 Ω	100 \pm 15%	145
			120 \pm 15%	190

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to terminals stated, all currents are defined positive into any lead. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Terminals	Max. Ratings	Units	Note
IDpeak	Drain Current *1	3-2	16	A	Single Pulse
IDMAX	Maximum switching current *5	3-2	16	A	V ₂₋₅ =0.78V
					Ta=-20~+125°C
EAS	Single pulse avalanche energy *2	3-2	327	mJ	Single Pulse
Vin	Input voltage for control part	4-5	35	V	
Vth	O.C.P/F.B Pin voltage	1-5	6	V	
PD1	Power dissipation for MOSFET *3	3-2	52	W	With infinite heatsink
			2.8	W	Without heatsink
PD2	Power dissipation for control part (Control IC) *4	4-5	0.49	W	Specified by Vin × Iin
					Refer to recommended operating temperature
TF	Internal frame temperature in operation	-	-20 ~ +125	°C	
Top	Operating ambient temperature	-	-20 ~ +125	°C	
Tstg	Storage temperature	-	-40 ~ +125	°C	
Tch	Channel temperature	-	150	°C	

*1 Refer to MOS FET A.S.O curve

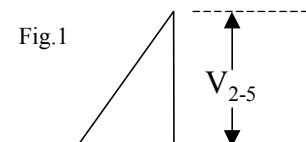
*2 MOS FET Tch-EAS curve

*3 Refer to MOS FET Ta-PD1 curve

*4 Refer to TF-PD2 curve for Control IC (See page 5)

*5 Maximum switching current.

The maximum switching current is the Drain current determined by the drive voltage of the IC and threshold voltage (Vth) of MOS FET. Therefore, in the event that voltage drop occurs between Pin 2 and Pin 5 due to patterning, the maximum switching current decreases as shown by V₂₋₅ in Fig.1. Accordingly please use this device within the decrease value, referring to the derating curve of the maximum switching current.



Electrical Characteristics (for Control IC)

Electrical characteristics for control part ($T_a=25^\circ C$, $V_{in}=18V$, unless otherwise specified)

Symbol	Definition	Ratings			Units	Test Conditions
		MIN	TYP	MAX		
$V_{in(ON)}$	Operation start voltage	14.4	16	17.6	V	$V_{in}=0 \rightarrow 17.6V$
$V_{in(OFF)}$	Operation stop voltage	9	10	11	V	$V_{in}=17.6 \rightarrow 9V$
$I_{in(ON)}$	Circuit current in operation	-	-	20	mA	-
$I_{in(OFF)}$	Circuit current in non-operation	-	-	100	μA	$V_{in}=14V$
$T_{OFF(MAX)}$	Maximum OFF time	45	-	55	μsec	-
$T_{th(2)}$	Minimum time for input of quasi resonant signals *6	-	-	1	μsec	-
$T_{OFF(MIN)}$	Minimum OFF time *7	-	-	2	μsec	-
$V_{th(1)}$	O.C.P/F.B Pin threshold voltage 1	0.68	0.73	0.78	V	-
$V_{th(2)}$	O.C.P/F.B Pin threshold voltage 2	1.3	1.45	1.6	V	-
$I_{OCP/FB}$	O.C.P/F.B Pin extraction current	1.2	1.35	1.5	mA	-
$V_{in(OVP)}$	O.V.P operation voltage	20.5	22.5	24.5	V	$V_{in}=0 \rightarrow 24.5V$
$I_{in(H)}$	Latch circuit sustaining current *8	-	-	400	μA	$V_{in}=24.5 \rightarrow 8.5V$
$V_{in(La.OFF)}$	Latch circuit release voltage *8	6.6	-	8.4	V	$V_{in}=24.5 \rightarrow 6.6V$
$T_j(TSD)$	Thermal shutdown operating temperature	140	-	-	$^\circ C$	-

*6 Refer to Recommended operating conditions

*7 The minimum OFF time means T_{OFF} width at the time when the minimum quasi resonant signal is inputted.

*8 The latch circuit means a circuit operated O.V.P and T.S.D.

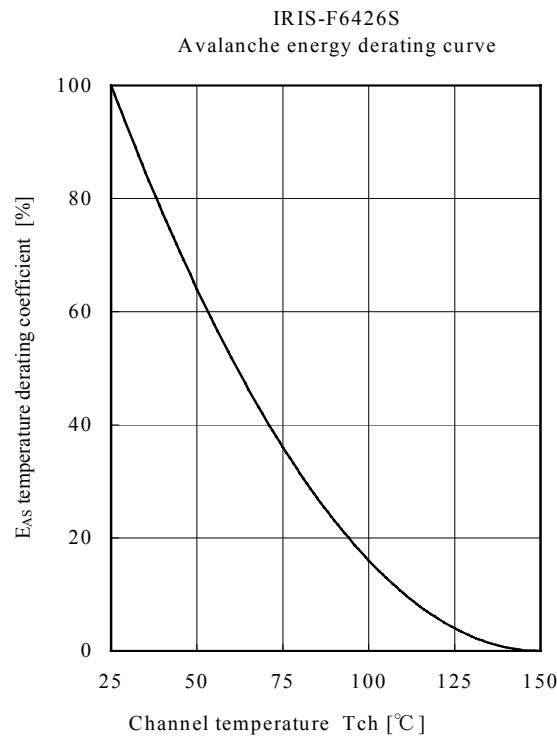
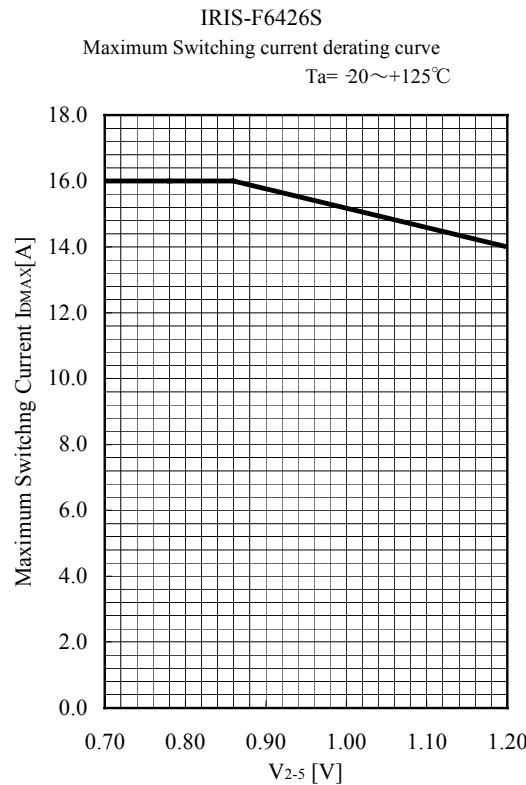
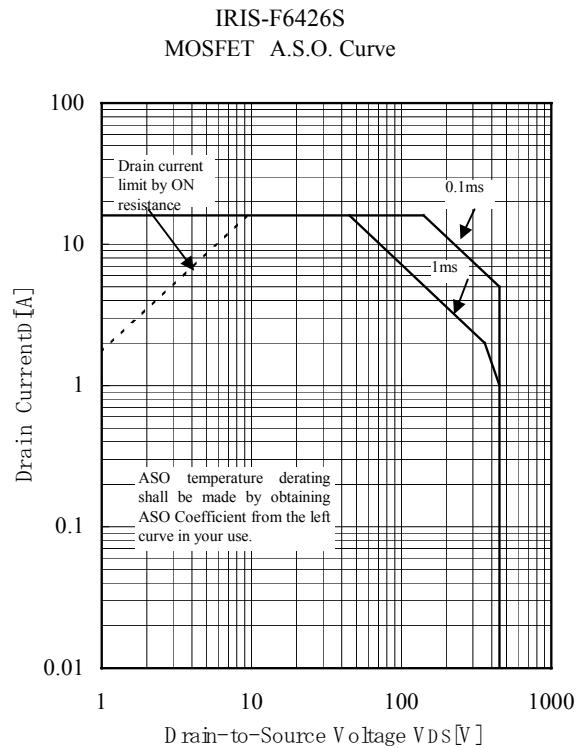
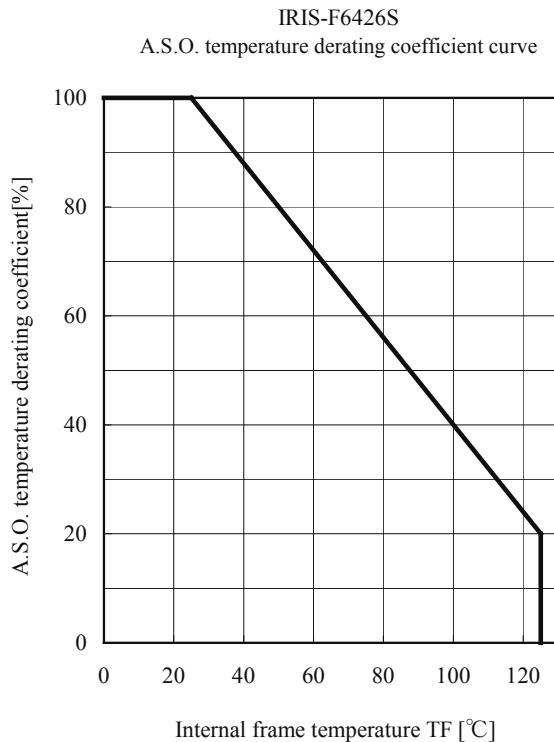
Electrical Characteristics (for MOSFET)

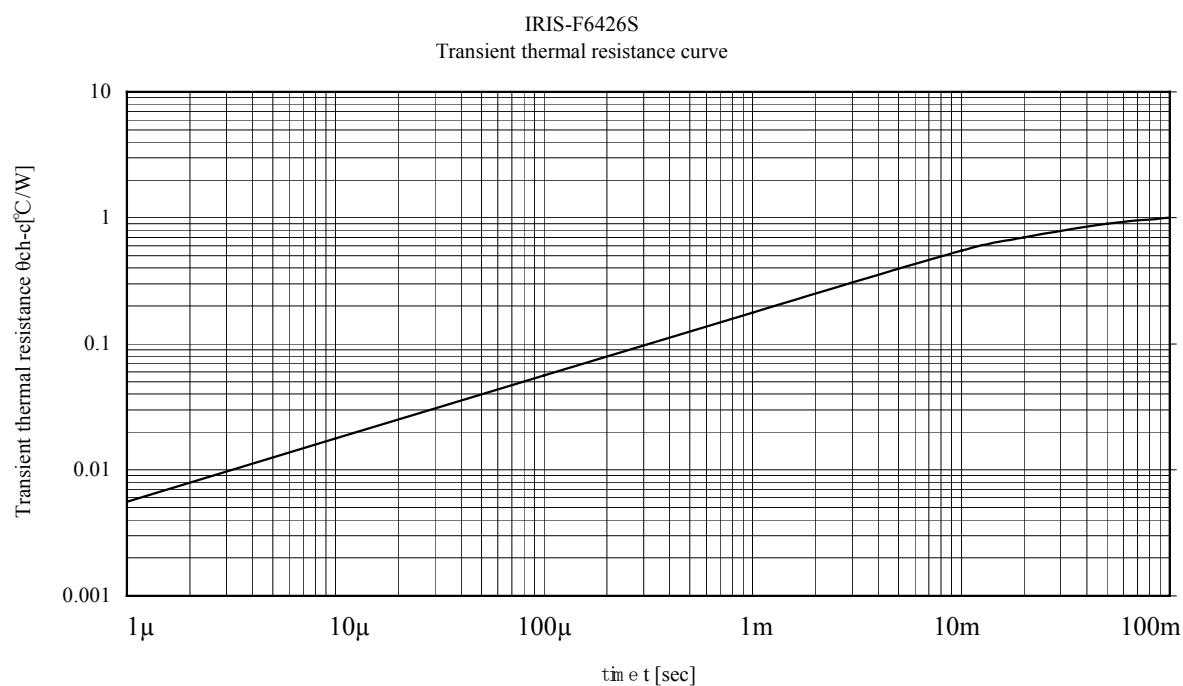
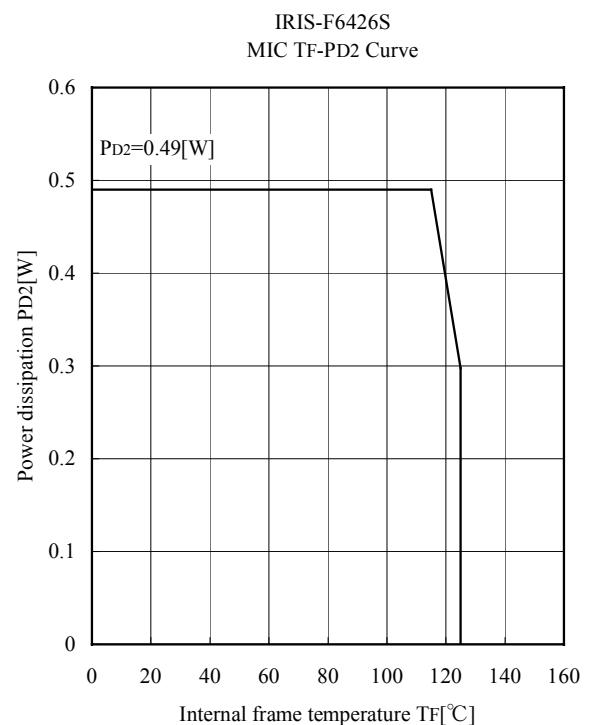
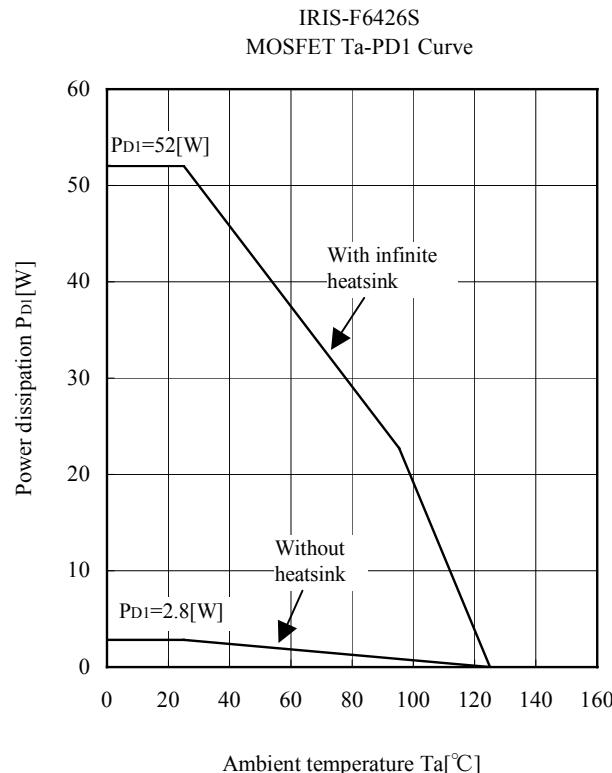
($T_a=25^\circ C$) unless otherwise specified

Symbol	Definition	Ratings			Units	Test Conditions
		MIN	TYP	MAX		
V_{DSS}	Drain-to-Source breakdown voltage	450	-	-	V	$ID=300\mu A$ $V_{5-2}=0V$ (short)
$IDSS$	Drain leakage current	-	-	300	μA	$V_{DS}=450V$ $V_{5-2}=0V$ (short)
$R_{DS(ON)}$	On-resistance	-	-	0.58	Ω	$V_{5-2}=10V$ $ID=3.3A$
t_f	Switching time	-	-	250	nsec	-
θ_{ch-F}	Thermal resistance	-	-	1.1	$^\circ C/W$	Between channel and internal frame

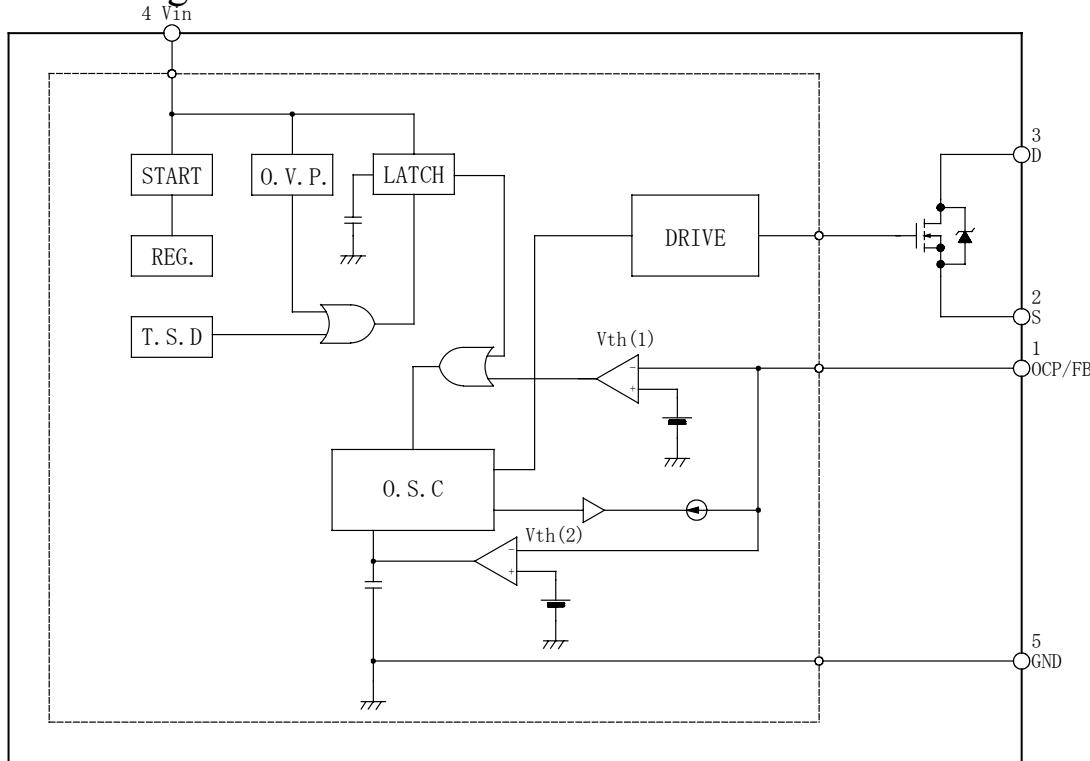
IRIS-F6426S

International
 Rectifier

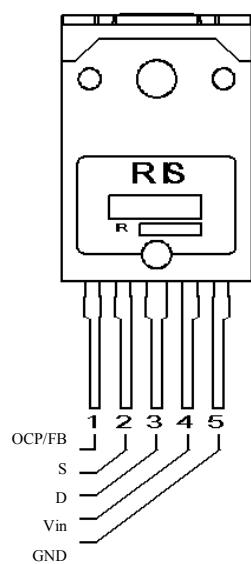




Block Diagram



Lead Assignments



Pin No.	Symbol	Description	Function
1	OCP/FB	Overcurrent / Feedback Pin	Input of overcurrent detection signal / constant voltage control signal
2	S	Source Pin	MOSFET source
3	D	Drain Pin	MOSFET drain
4	Vin	Power supply Pin	Input of power supply for control circuit
5	GND	Ground Pin	Ground

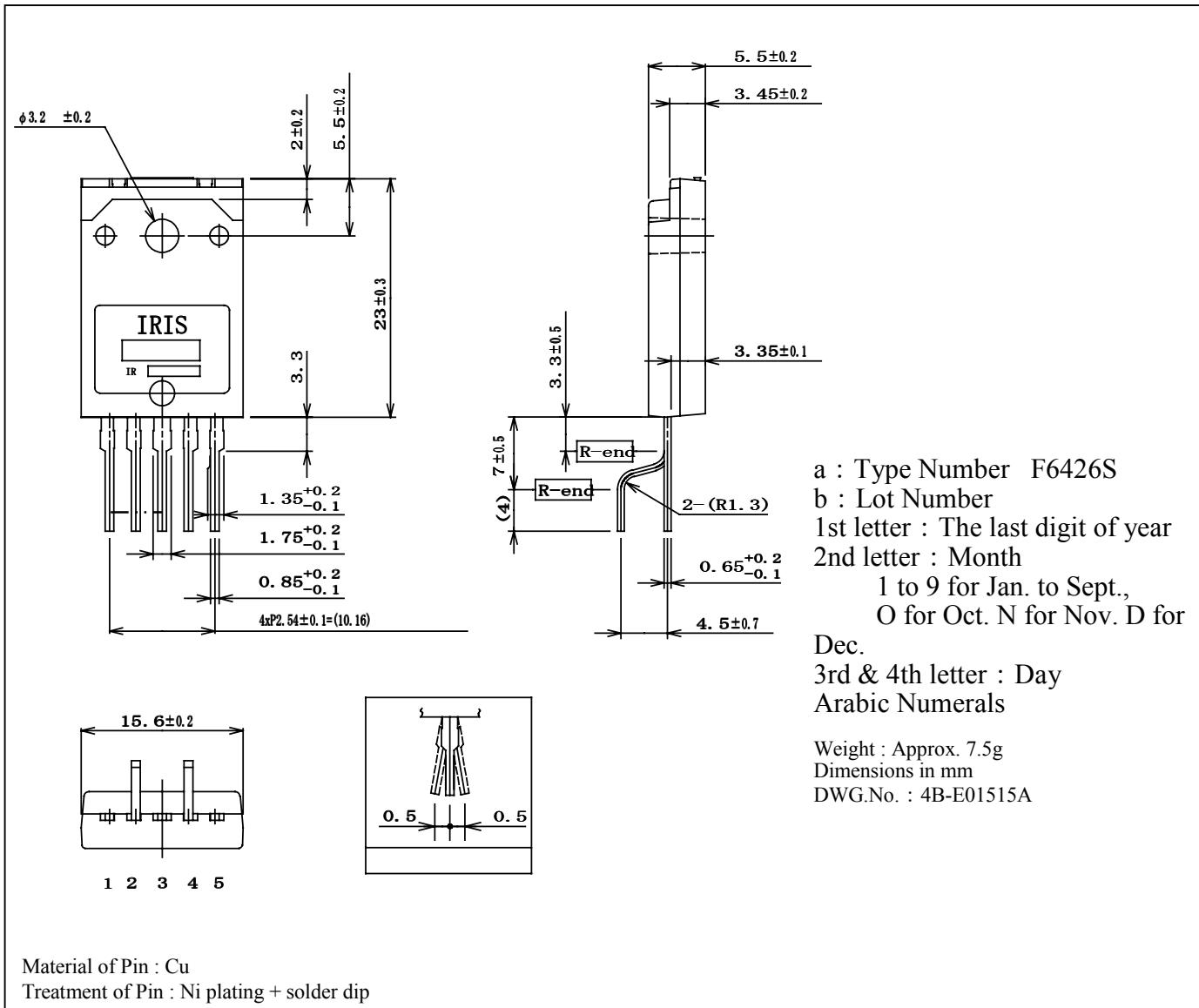
Other Functions

O.V.P. – Overvoltage Protection Circuit

T.S.D. – Thermal Shutdown Circuit

STEP DRV – 2 step drive circuit

Case Outline



Data and specifications subject to change without notice.

International
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